

FMPBSS5160

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FMPBSS5160

-1.0A -60V Transistor PNP Silicon

Features

- Low $V_{CE(sat)}$, high current.
- Lead-free parts meet RoHS requirements.
- Suffix "-H" indicates Halogen free parts, ex. FMPBSS5160-H.

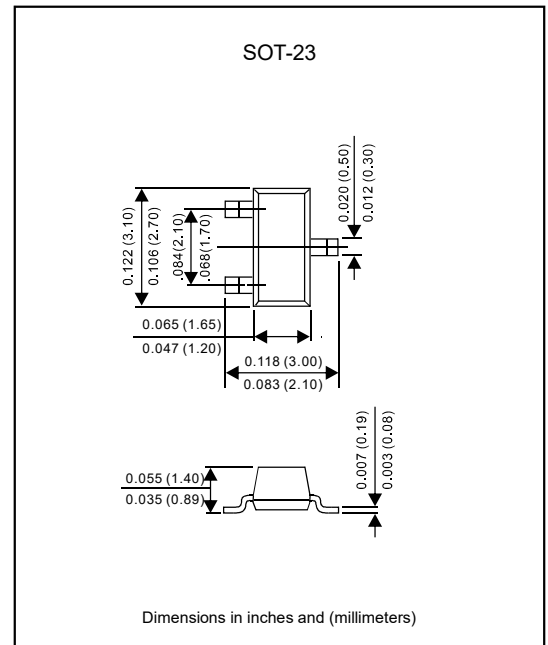
Applications

- General purpose switching and muting.
- LCD back-lighting.
- Supply line switching circuits.

Mechanical data

- Epoxy: UL94-V0 rated flame retardant.
- Case : Molded plastic, SOT-23.
- Terminals : Solder plated, solderable per MIL-STD-750, Method 2026.
- Mounting Position : Any.

Package outline



Maximum ratings (At $T_A=25^\circ\text{C}$ unless otherwise noted)

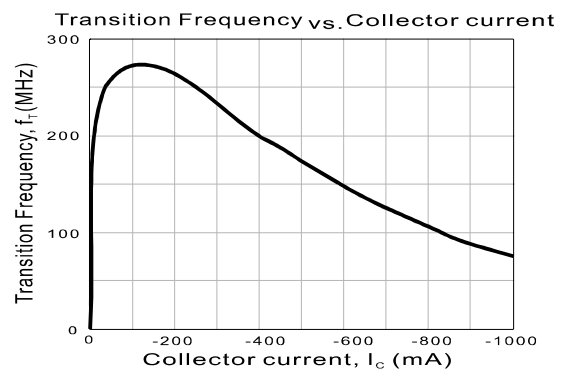
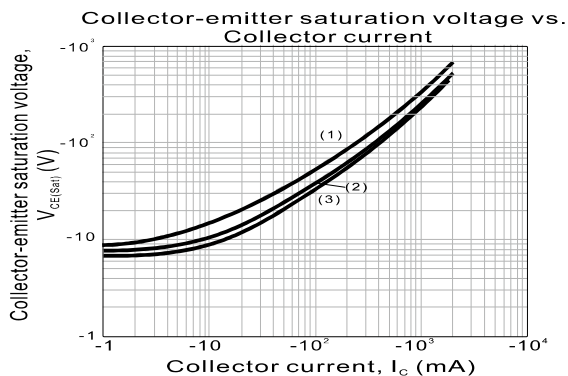
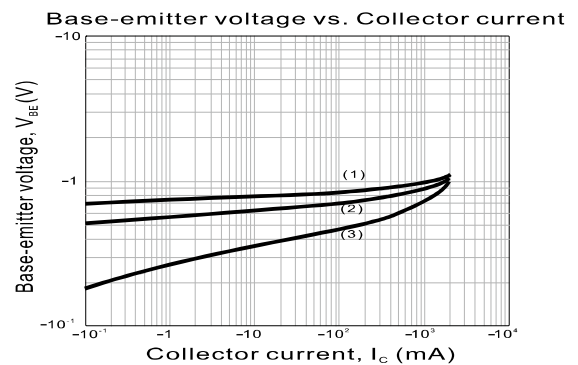
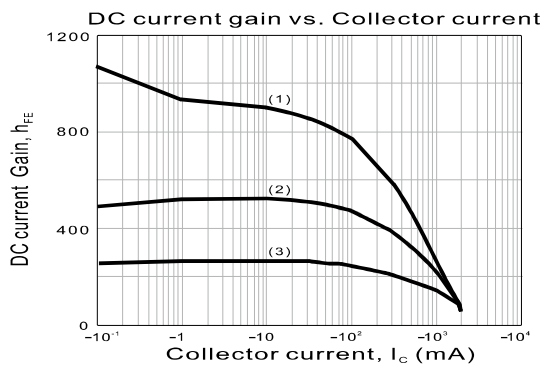
Parameter	Symbol	Ratings	Unit
Collector to base voltage	$-V_{CBO}$	80	V
Collector to Emitter Voltage	$-V_{CEO}$	60	V
Emitter to base voltage	$-V_{EBO}$	5	V
Collector current	$-I_C$	1	A
Peak collector current	$-I_{CM}$	2	A
Base current	$-I_B$	0.3	A
Peak base current	$-I_{BM}$	1	A
Collector power dissipation	P_C	400	mW
Junction temperature	T_J	+150	$^\circ\text{C}$
Storage temperature range	T_{STG}	-55 to +150	$^\circ\text{C}$

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Electrical characteristics (At $T_A=25^\circ\text{C}$ unless otherwise noted)

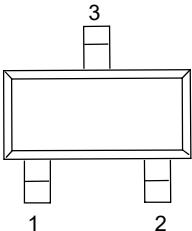
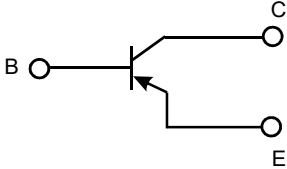
Parameter	Conditions	Symbol	Min	Typ	Max	Unit
Collector-base cut off current	$-V_{CB} = 60\text{V}, I_E = 0\text{A}$	$-I_{CBO}$			0.1	μA
	$-V_{CB} = 60\text{V}, I_E = 0\text{A}, T_J=150^\circ\text{C}$				50	
Collector-emitter cut off current	$-V_{CE} = 60\text{V}, V_{BE} = 0\text{V}$	$-I_{CEO}$			0.1	μA
Emitter-base cut off current	$-V_{EB} = 5\text{V}, I_C = 0\text{A}$	$-I_{EBO}$			0.1	μA
Collector-emitter saturation voltage	$-I_C = 100\text{mA}, -I_B = 1.0\text{mA}$	$-V_{CE(sat)(1)}$		110	160	mV
	$-I_C = 500\text{mA}, -I_B = 50\text{mA}$	$-V_{CE(sat)(2)}$		120	175	
	$-I_C = 1\text{A}, -I_B = 100\text{mA}$	$-V_{CE(sat)(3)}$		220	330	
Base-emitter voltage	$-V_{CE} = 5\text{V}, -I_C = 1\text{A}$	$-V_{BE}$		0.82	0.9	V
Base-emitter saturation voltage	$-I_C = 1\text{A}, -I_B = 50\text{mA}$	$-V_{BE(sat)}$		0.95	1.1	V
DC current gain	$-V_{CE}=5\text{V}, -I_C=500\text{mA}$	$h_{FE(1)}$	150	250		
	$-V_{CE}=5\text{V}, -I_C=1\text{mA}$	$h_{FE(2)}$	200	350		
	$-V_{CE}=5\text{V}, -I_C=1\text{A}$	$h_{FE(3)}$	100	160		
Transition Frequency	$-V_{CE}=10\text{V}, -I_C=50\text{mA}, f=100\text{MHz}$	f_T	150	220		MHz
Output capacitance	$-V_{CB}=10\text{V}, I_E=0\text{A}, f=1.0\text{MHz}$	C_C		9	15	pF

Rating and characteristic curves



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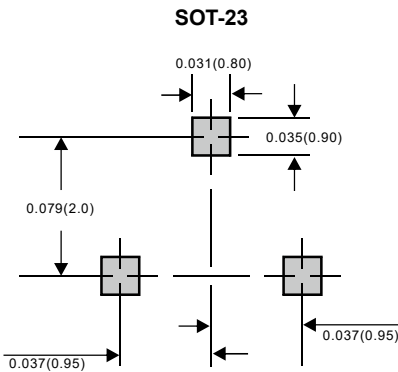
Pinning information

Pin	Simplified outline	Symbol
Pin 1 Base Pin 2 Emitter Pin 3 Collector		

Marking and h_{FE} range

Type number	Marking code	DC current gain range (h_{FE})
FMPBSS5160	HU6	>150

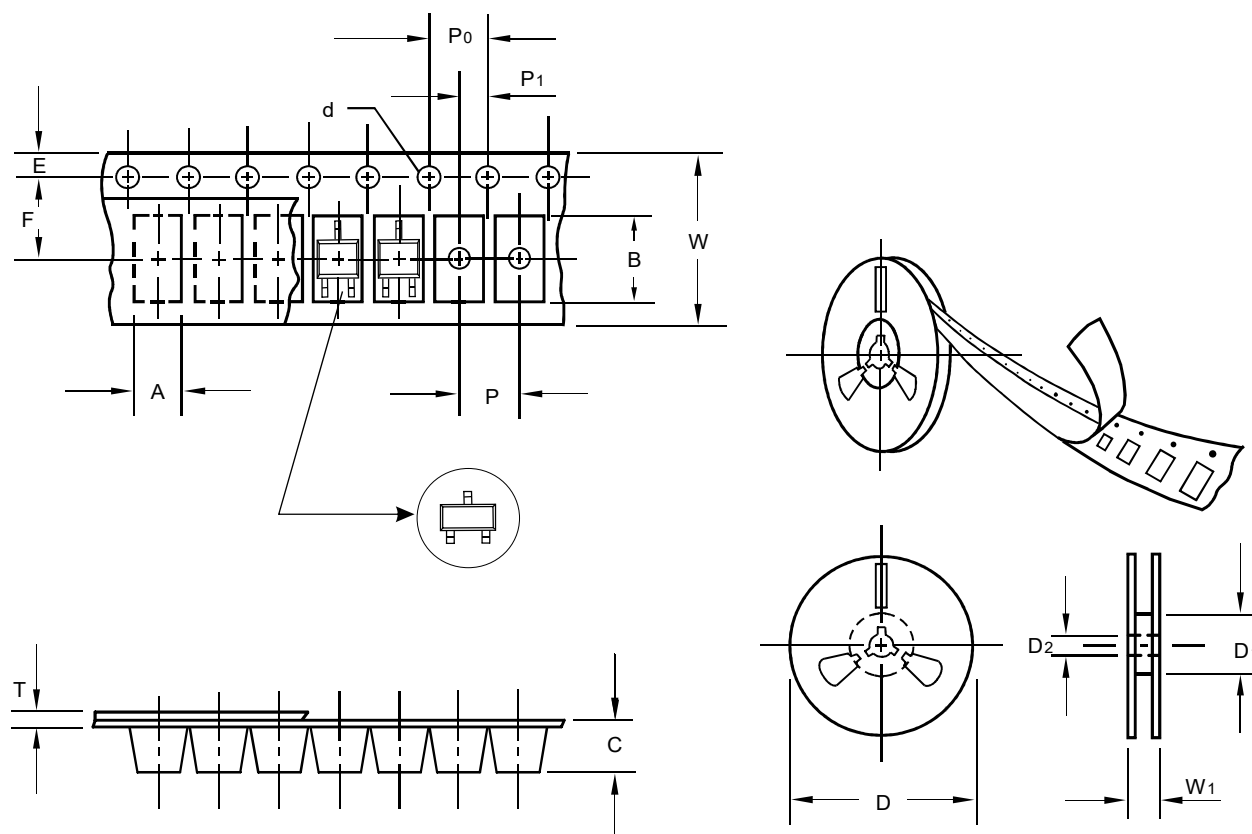
Suggested solder pad layout



Dimensions in inches and (millimeters)

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Packing information



unit:mm

Item	Symbol	Tolerance	SOT-23
Carrier width	A	0.3	3.30
Carrier length	B	0.3	3.20
Carrier depth	C	0.3	1.50
Sprocket hole	d	0.1	1.50
13" Reel outside diameter	D	2.0	-
13" Reel inner diameter	D1	min	-
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D1	min	54.40
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	3.50
Punch hole pitch	P	0.1	4.00
Sprocket hole pitch	P0	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	T	0.1	0.23
Tape width	W	0.3	8.00
Reel width	W1	1.0	12.0

Note: Devices are packed in accordance with EIA standard RS-481-A and specifications listed above.

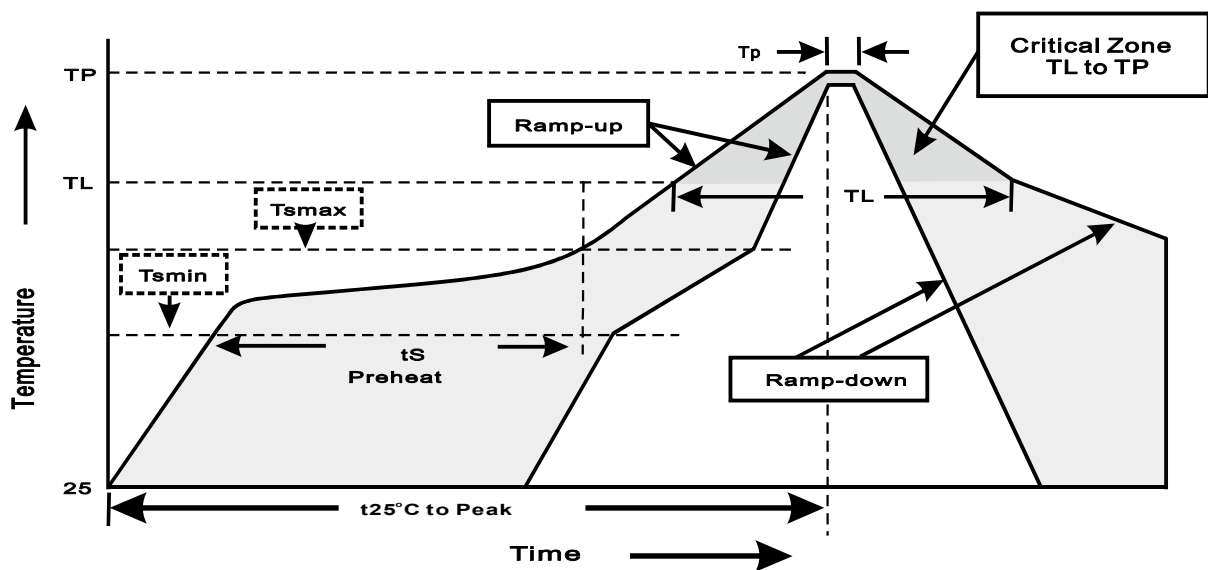
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Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)
SOT-23	7"	3,000	4.0	30,000	183*123*183	178	382*257*387	240,000

Suggested thermal profiles for soldering processes

- Storage environment: Temperature=5°C~40°C Humidity=55%±25%
- Reflow soldering of surface-mount devices



3. Reflow soldering

Profile Feature	Soldering Condition
Average ramp-up rate(T_L to T_P)	<3°C/sec
Preheat - Temperature Min(T_{smin}) - Temperature Max(T_{smax}) - Time(min to max)(t_s)	150°C 200°C 60~120sec
T_{smax} to T_L - Ramp-upRate	<3°C/sec
Time maintained above: - Temperature(T_L) - Time(t_L)	217°C 60~260sec
Peak Temperature(T_P)	255°C-0/+5°C
Time within 5°C of actual Peak Temperature(t_P)	10~30sec
Ramp-down Rate	<6°C/sec
Time 25°C to Peak Temperature	<6minutes